

Features

- Low forward voltage drop
- High reverse voltage
- Hermetic metal cases with ceramic insulators

Typical Applications

- All purpose high power rectifier diodes
- High power resistance welding equipment
- Non-controllable and half-controllable rectifiers
- Controlled rectifiers

$I_{F(AV)}$	860A
V_{RRM}	200~1000V
I_{FSM}	8 kA
I^2t	320 $10^3 A^2S$



SYMBOL	CHARACTERISTIC	TEST CONDITIONS	$T_j(^{\circ}C)$	VALUE			UNIT
				Min	Type	Max	
$I_{F(AV)}$	Mean forward current	180° half sine wave 50Hz Double side cooled,	$T_c=85^{\circ}C$	190		860	A
V_{RRM}	Repetitive peak reverse voltage	tp=10ms	190	200		1000	V
I_{RRM}	Repetitive peak current	at V_{RRM}	190			16	mA
I_{FSM}	Surge forward current	10ms half sine wave	190			8	kA
I^2t	I^2t for fusing coordination	$V_R=0.6V_{RRM}$				320	$A^2s \times 10^3$
V_{FO}	Threshold voltage		190			0.80	V
r_F	Forward slope resistance					0.34	$m\Omega$
V_{FM}	Peak forward voltage	$I_{FM}=600A, F=5.0kN$	25			1.80	V
Q_{fr}	Recovery charge	$I_{FM}=1000A, tp=2000\mu s, di/dt=-20A/\mu s, V_R=50V$	190		1400		μC
$R_{th(j-c)}$	Thermal resistance Junction to case	At 180° sine double side cooled Clamping force 5.0kN				0.080	$^{\circ}C / W$
$R_{th(c-h)}$	Thermal resistance case to heat sink					0.020	
F_m	Mounting force				3.3	5.5	kN
T_{stg}	Stored temperature			-40		190	$^{\circ}C$
W_t	Weight				60		g
Outline		ZT19aT					

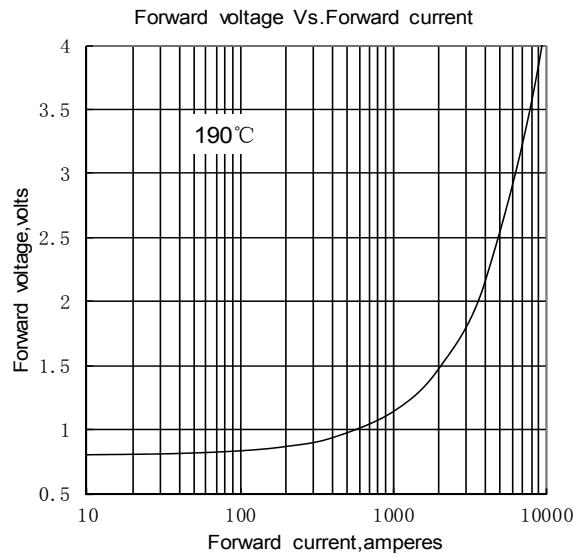


Fig1

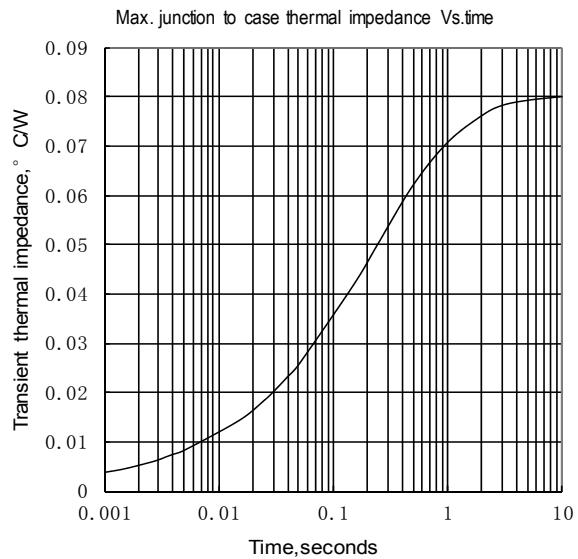


Fig2

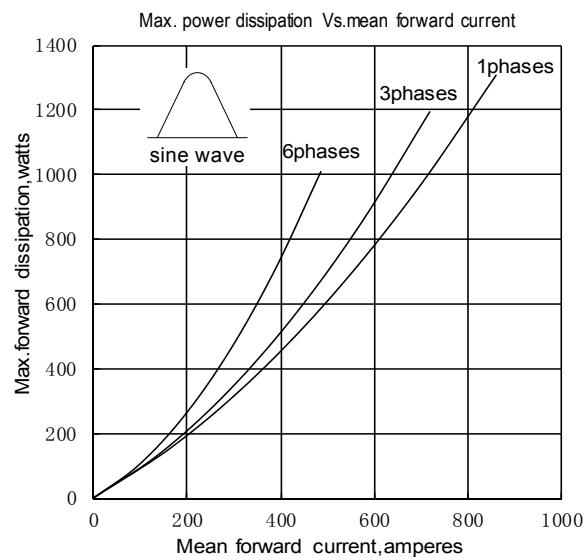


Fig3

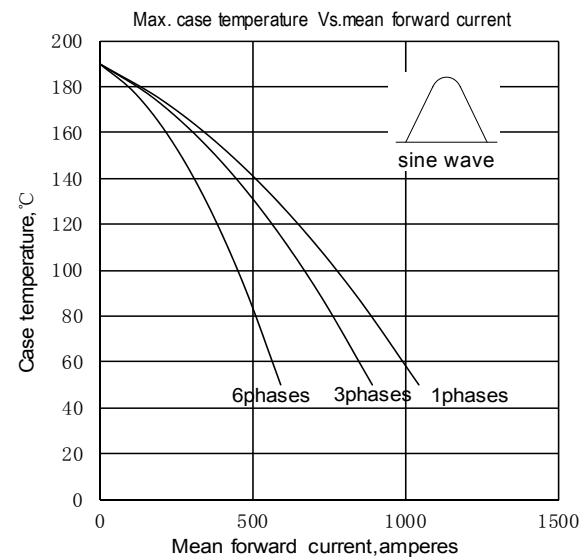


Fig4

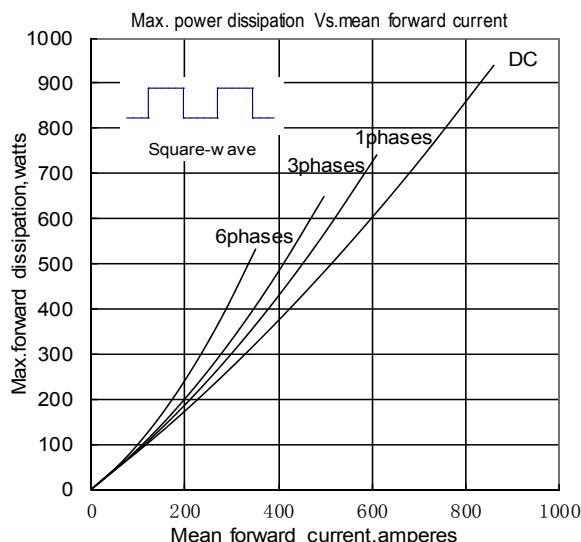


Fig5

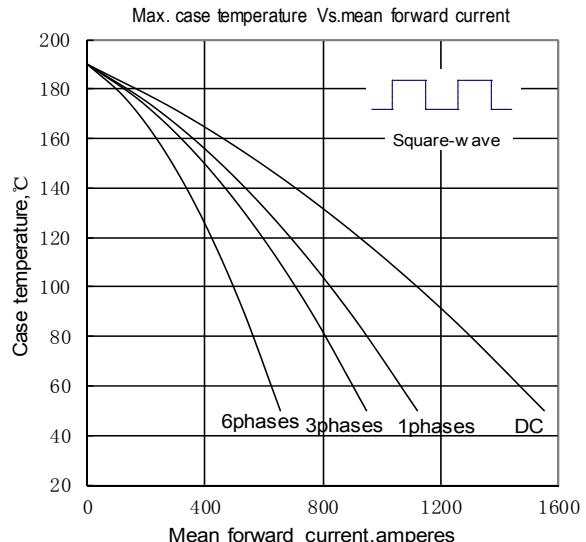


Fig6

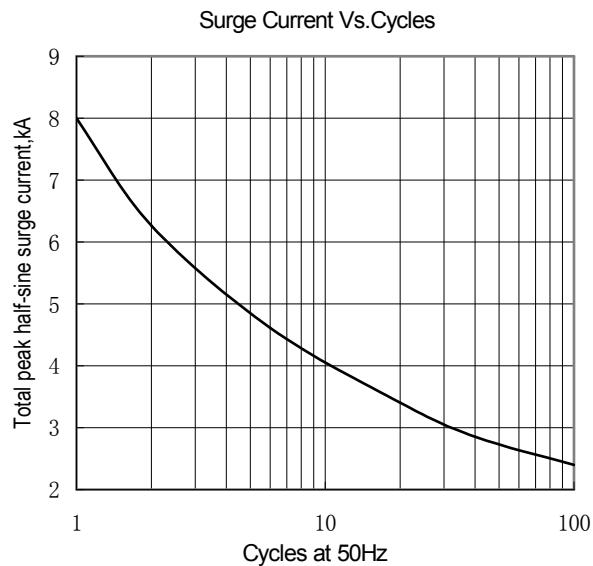


Fig.7

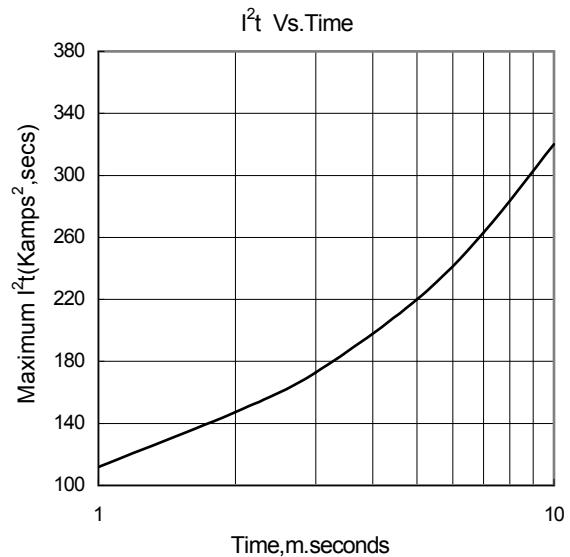


Fig.8

Outline: